# **Darlington**

# 2SB1560



### Silicon PNP Epitaxial Planar Transistor (Complement to type 2SD2390)

#### Application: Audio, Series Regulator and General Purpose

Absolute maximum ratings		(Ta=25°C)		
Symbol	2SB1560		Unit	

Symbol	2SB1560	Unit
Vсво	-160	V
VCEO	-150	V
VEBO	-5	V
Ic	-10	А
Ів	-1	А
Pc	100(Tc=25°C)	W
Tj	150	°C
Tstg	-55 to +150	°C

#### Electrical Characteristics

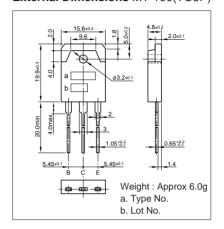
Electrical C	(Ta	Ta=25°C)	
Symbol	Conditions	2SB1560	Unit
Ісво	VcB=-160V	-100max	μΑ
<b>І</b> ЕВО	V <sub>EB</sub> =-5V	-100max	μΑ
V(BR)CEO	Ic=-30mA	-150min	V
hfe	Vce=-4V, Ic=-7A	5000min*	
Vce(sat)	Ic=-7A, IB=-7mA	-2.5max	V
VBE(sat)	Ic=-7A, IB=-7mA	-3.0max	V
fr	Vce=-12V, Ie=2A	50typ	MHz
Сов	VcB=-10V, f=1MHz	230typ	pF

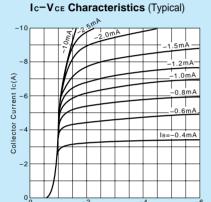
\*hfe Rank 0(5000 to 12000), P(6500 to 20000), Y(15000 to 30000)

#### Typical Switching Characteristics (Common Emitter)

Vcc (V)	RL (Ω)	Ic (A)	V <sub>BB1</sub> (V)	V <sub>BB2</sub> (V)	I <sub>B1</sub> (mA)	I <sub>B2</sub> (mA)	ton (µs)	tstg (µs)	tf (µs)
-70	10	-7	-10	5	-7	7	0.8typ	3.0typ	1.2typ

## External Dimensions MT-100(TO3P)





Collector-Emitter Voltage VcE(V)

